

PSD10: 10th International Conference on Position Sensitive Detectors

Friday, September 12, 2014

Session 15: Detectors for High Radiation and Extreme Environments - AP1&2 (8:30 AM - 10:30 AM)

time	[id] title	presenter
8:30 AM	M123] (Invited) Direct-detection Monolithic Active CMOS sensors for X-ray Free-Electron Lasers and future ultimate storage ring light sources	HATSUI, Takaki
9:10 AM	M106] Optimization of charge collection and radiation hardness of edgeless silicon pixel sensors for photon science and HEP applications	Dr ZHANG, Jiaguo
9:30 AM	M122] Charge Collection Efficiency of micro-strip Silicon Sensors Designed for studying charge multiplication after hadron irradiation	WONSAK, Sven
9:50 AM	M108] Studying defects in the silicon lattice using CCDs	HALL, David
10:10 AM	M101] Thin n-in-p planar pixel sensors and active edge sensors for the ATLAS upgrade at HL-LHC	TERZO, Stefano